

SURFACE MOUNT FAST SWITCHING RECTIFIER

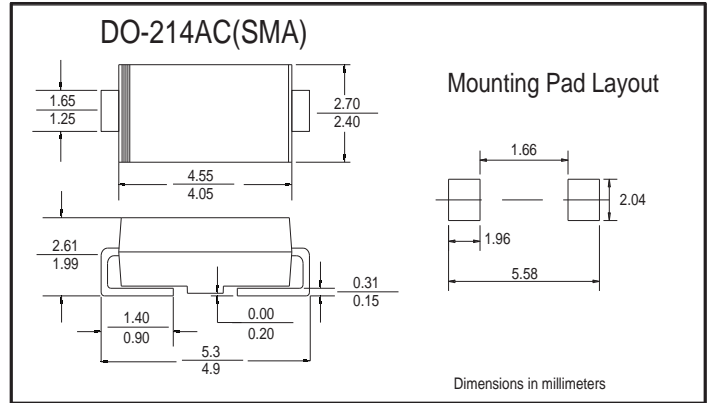
Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere

Features

- For surface mounted application
- Metal to silicon rectifier, majority carrier conduction
- Low forward voltage drop
- Easy pick and place
- High surge current capability
- Plastic material used carriers Underwriters Laboratory Classification 94-O
- Epitaxial construction
- High temperature soldering: 250°C/10 seconds at terminals

Mechanical Data

- Case: molded plastic
- Terminals: Solder plated
- Polarity: Indicated by cathode band
- Packaging: 12mm tape EIA STD RS-481
- Weight: 0.064gram



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number		RS1A	RS1B	RS1D	RS1G	RS1J	RS1K	RS1M	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ $T_i=90^\circ\text{C}$	$I_{F(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage (Note @ 1.0 A)	V_F	1.3							V
Maximum DC Reverse Current @ $T_A, T_J=25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A=125^\circ\text{C}$	I_R	5.0 50							μA
Maximum Reverse Recovery Time (Note 1)	T_{RR}	150				250	500		nS
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$ $R_{\theta JA}$	25 55							$^\circ\text{C/W}$
Operating Junction Temperature Range	T_J	-55 to +125							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150							$^\circ\text{C}$

NOTES: 1. Reverse Recovery Test conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$.

2. Thermal Resistance from Junction to Ambient and from Junction to Lead Mounted on P.C.B. with 0.2"x0.2" (5.0 x 5.0 mm) Copper Pad Areas.

■ Characteristics(Typical)

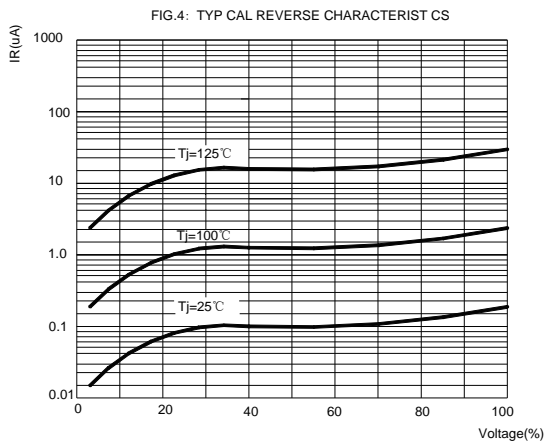
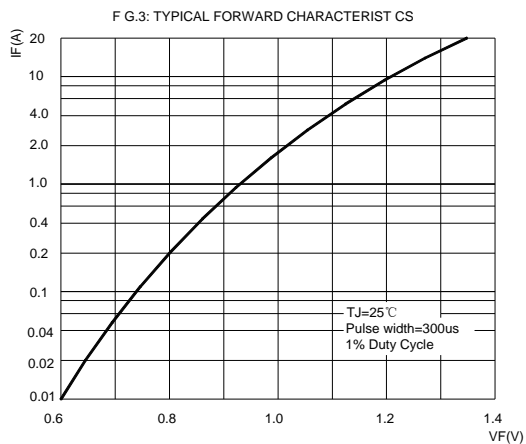
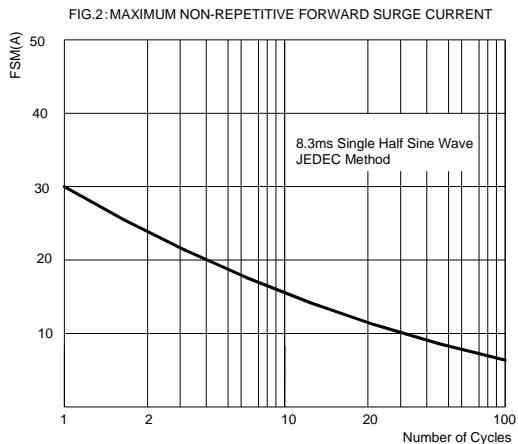
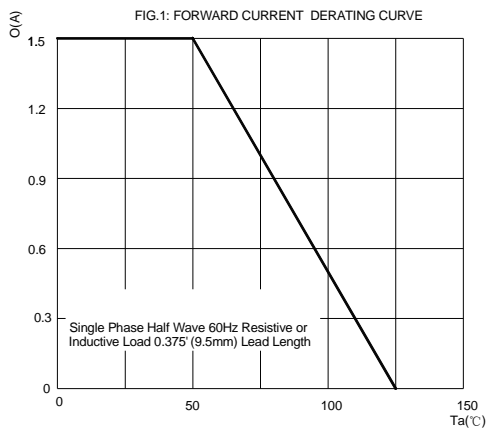


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

